

SILICON POWER TRANSISTOR 2SA1647, 1647-Z

PNP SILICON EPITAXIAL TRANSISTOR FOR HIGH-SPEED SWITCHING

DESCRIPTION

The 2SA1647 is a mold power transistor developed for high-speed switching and features a very low collector-to-emitter saturation voltage.

This transistor is ideal for use in switching regulators, DC/DC converters, motor drivers, solenoid drivers, and other low-voltage power supply devices, as well as for high-current switching.

FEATURES

- Available for high-current control in small dimension
- Z type is a lead processed product and is deal for mounting a hybrid IC.
- Low collector saturation voltage:
 $V_{CE(sat)1} = -0.3 \text{ V MAX. (Ic} = -3.0 \text{ A)}$
- Fast switching speed:
 $t_r = 0.4 \mu\text{s MAX. (Ic} = -3.0 \text{ A)}$
- High DC current gain and excellent linearity

ABSOLUTE MAXIMUM RATINGS (T_A = 25°C)

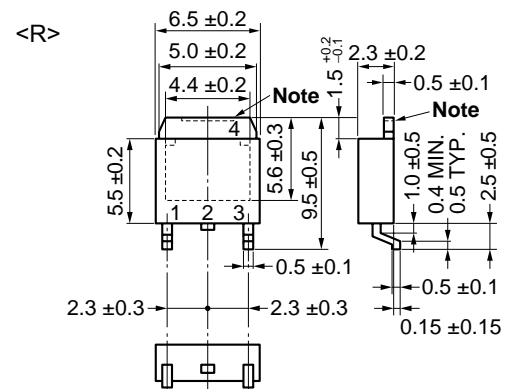
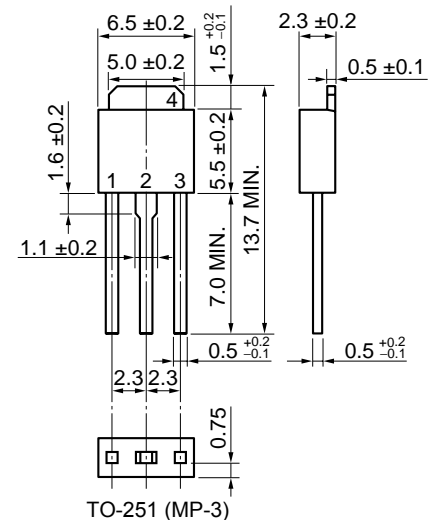
Parameter	Symbol	Rated	Unit
Collector to base voltage	V _{CBO}	-150	V
Collector to emitter voltage	V _{CEO}	-100	V
Base to emitter voltage	V _{EBO}	-7.0	V
Collector current (DC)	I _{C(DC)}	-5.0	A
Collector current (pulse)	I _{C(pulse)} ^{Note 1}	-10	A
Base current (DC)	I _{B(DC)}	-2.5	A
Total power dissipation (T _c = 25°C)	P _T	18	W
Total power dissipation (T _A = 25°C)	P _T	1.0 ^{Note 2} , 2.0 ^{Note 3}	W
Junction temperature	T _j	150	°C
Storage temperature	T _{stg}	-55 to +150	°C

Notes 1. PW ≤ 10 ms, Duty Cycle ≤ 50%

2. Printing board mounted

3. 7.5 cm² × 0.7 mm ceramic board mounted

PACKAGE DRAWINGS (Unit: mm)



ELECTRODE CONNECTION

1. Base
2. Collector
3. Emitter
4. Collector Fin

Note The depth of notch at the top of the fin is from 0 to 0.2 mm.

The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version.
Not all products and/or types are available in every country. Please check with an NEC Electronics sales representative for availability and additional information.

ELECTRICAL CHARACTERISTICS (T_A = 25°C)

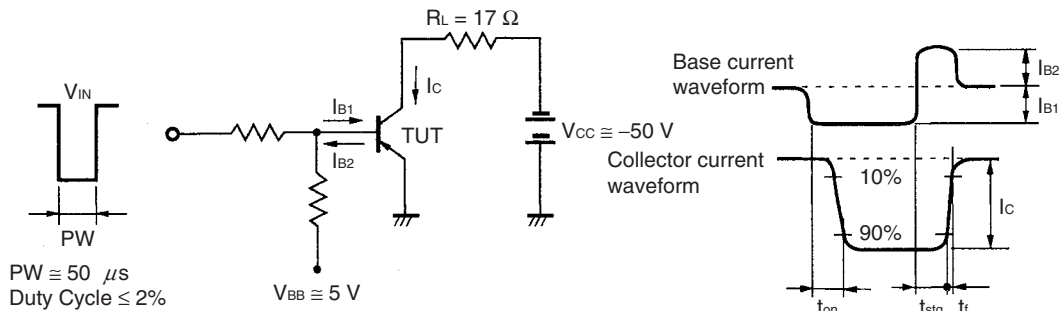
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector to emitter voltage	V _{CE0(SUS)}	I _C = -2.5 A, I _B = -0.25 A, L = 1 mH	-100			V
Collector to emitter voltage	V _{CEx(SUS)}	I _C = -2.5 A, I _{B1} = -I _{B2} = -0.25 A, V _{BE(OFF)} = 1.5 V, L = 180 μH, clamped	-100			V
Collector cutoff current	I _{CBO}	V _{CB} = -100 V, I _E = 0 A			-10	μA
Collector cutoff current	I _{CER}	V _{CE} = -100 V, R _{BE} = 50 Ω, T _A = 125°C			-1.0	mA
Collector cutoff current	I _{CEx1}	V _{CE} = -100 V, V _{BE(OFF)} = 1.5 V			-10	μA
Collector cutoff current	I _{CEx2}	V _{CE} = -100 V, V _{BE(OFF)} = 1.5 V, T _A = 125°C			-1.0	mA
Emitter cutoff current	I _{EBO}	V _{EB(OFF)} = -5.0 V, I _C = 0 A			-10	μA
DC current gain	h _{FE1} ^{Note}	V _{CE} = -2.0 V, I _C = -0.5 A	100			
DC current gain	h _{FE2} ^{Note}	V _{CE} = -2.0 V, I _C = -1.0 A	100		400	
DC current gain	h _{FE3} ^{Note}	V _{CE} = -2.0 V, I _C = -3.0 A	60			
Collector saturation voltage	V _{CE(sat)1} ^{Note}	I _C = -3.0 A, I _B = -0.15 A			-0.3	V
Collector saturation voltage	V _{CE(sat)2} ^{Note}	I _C = -4.0 A, I _B = -0.2 A			-0.5	V
Base saturation voltage	V _{BE(sat)1} ^{Note}	I _C = -3.0 A, I _B = -0.15 A			-1.2	V
Base saturation voltage	V _{BE(sat)2} ^{Note}	I _C = -4.0 A, I _B = -0.2 A			-1.5	V
Collector capacitance	C _{ob}	V _{CB} = -10 V, I _E = 0, f = 1.0 MHz		110		pF
Gain bandwidth product	f _r	V _{CE} = -10 V, I _C = 0.5 A		90		MHz
Turn-on time	t _{on}	I _C = -3.0 A, R _L = 17 Ω, I _{B1} = -I _{B2} = -0.15 A, V _{CC} ≅ -50 V Refer to SWITCHING TIME TEST CIRCUIT.			0.3	μs
Storage time	t _{stg}				1.5	μs
Fall time	t _f				0.4	μs

Note Pulse test PW ≤ 350 μs, Duty Cycle ≤ 2%/Pulsed

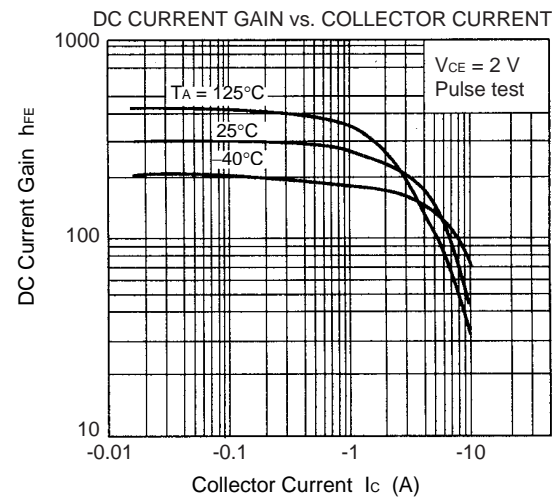
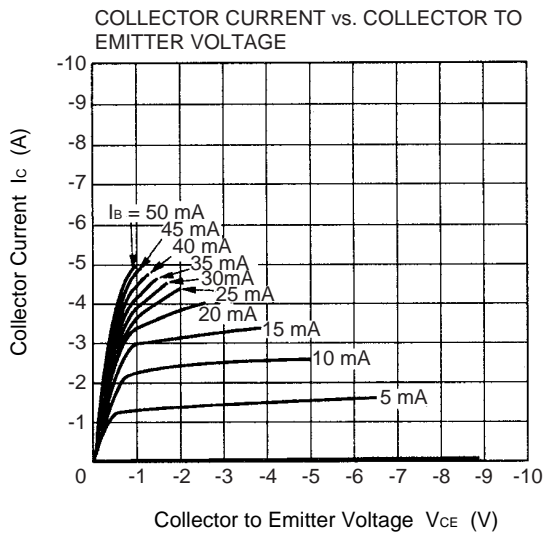
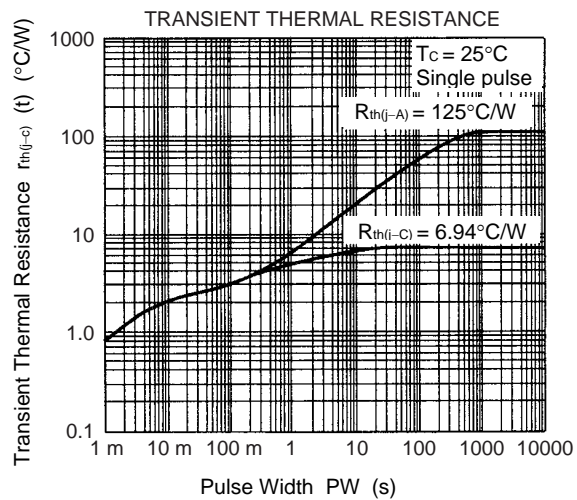
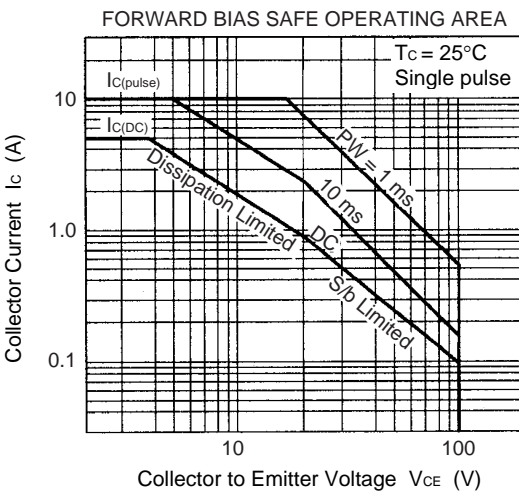
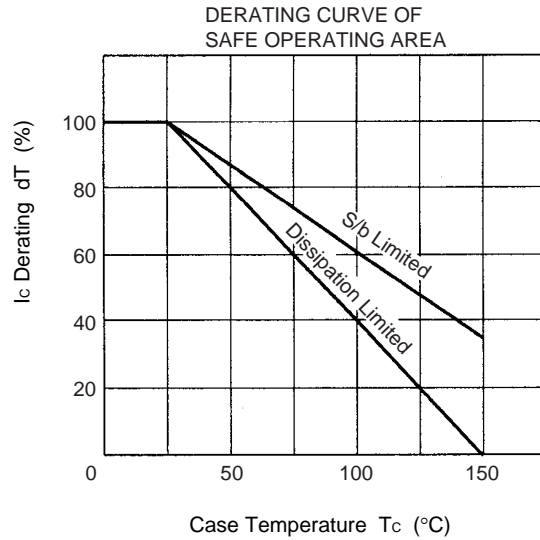
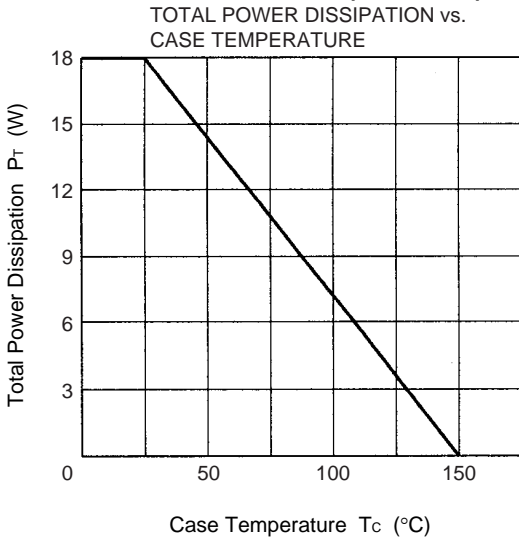
h_{FE} CLASSIFICATION

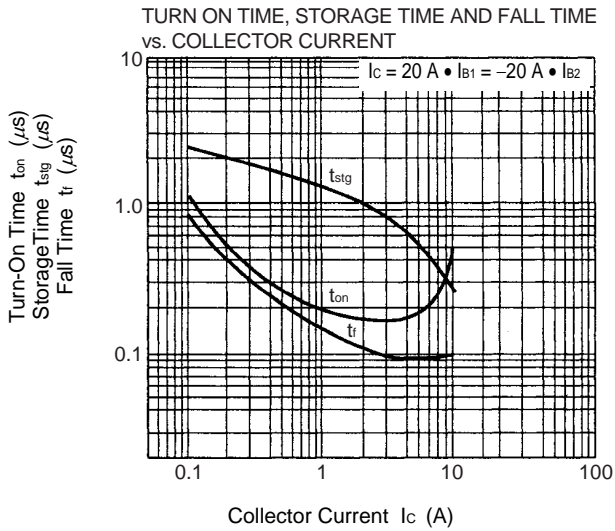
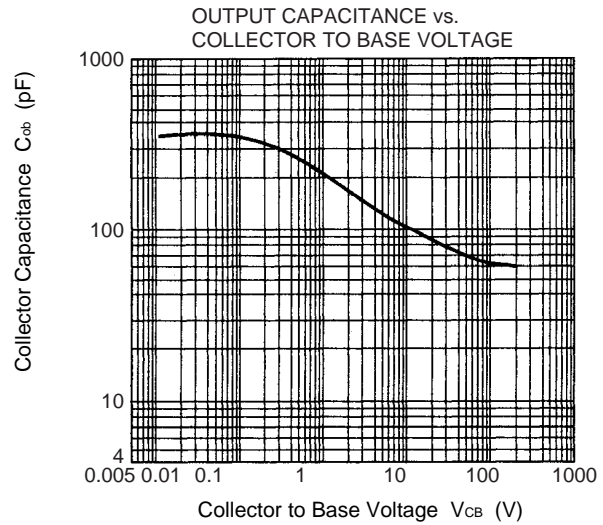
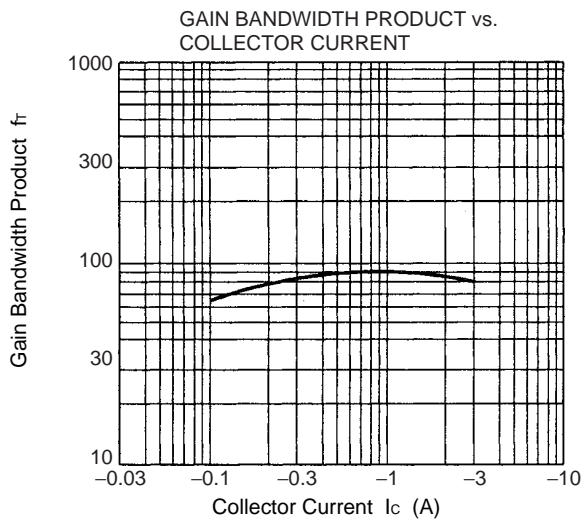
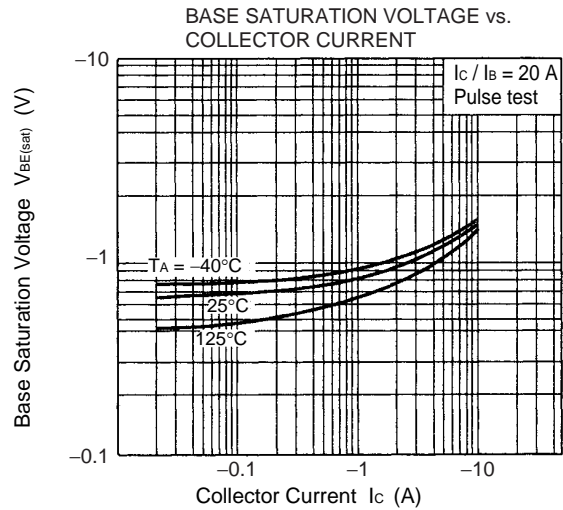
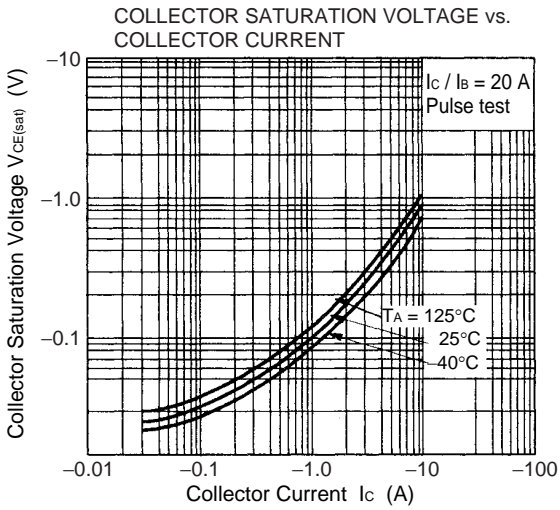
Marking	M	L	K
h _{FE2}	100 to 200	150 to 300	200 to 400

SWITCHING TIME TEST CIRCUIT



TYPICAL CHARACTERISTICS (T_A = 25°C)





- **The information in this document is current as of June, 2006. The information is subject to change without notice. For actual design-in, refer to the latest publications of NEC Electronics data sheets or data books, etc., for the most up-to-date specifications of NEC Electronics products. Not all products and/or types are available in every country. Please check with an NEC Electronics sales representative for availability and additional information.**

- No part of this document may be copied or reproduced in any form or by any means without the prior written consent of NEC Electronics. NEC Electronics assumes no responsibility for any errors that may appear in this document.
- NEC Electronics does not assume any liability for infringement of patents, copyrights or other intellectual property rights of third parties by or arising from the use of NEC Electronics products listed in this document or any other liability arising from the use of such products. No license, express, implied or otherwise, is granted under any patents, copyrights or other intellectual property rights of NEC Electronics or others.
- Descriptions of circuits, software and other related information in this document are provided for illustrative purposes in semiconductor product operation and application examples. The incorporation of these circuits, software and information in the design of a customer's equipment shall be done under the full responsibility of the customer. NEC Electronics assumes no responsibility for any losses incurred by customers or third parties arising from the use of these circuits, software and information.
- While NEC Electronics endeavors to enhance the quality, reliability and safety of NEC Electronics products, customers agree and acknowledge that the possibility of defects thereof cannot be eliminated entirely. To minimize risks of damage to property or injury (including death) to persons arising from defects in NEC Electronics products, customers must incorporate sufficient safety measures in their design, such as redundancy, fire-containment and anti-failure features.
- NEC Electronics products are classified into the following three quality grades: "Standard", "Special" and "Specific".

The "Specific" quality grade applies only to NEC Electronics products developed based on a customer-designated "quality assurance program" for a specific application. The recommended applications of an NEC Electronics product depend on its quality grade, as indicated below. Customers must check the quality grade of each NEC Electronics product before using it in a particular application.

"Standard": Computers, office equipment, communications equipment, test and measurement equipment, audio and visual equipment, home electronic appliances, machine tools, personal electronic equipment and industrial robots.

"Special": Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support).

"Specific": Aircraft, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems and medical equipment for life support, etc.

The quality grade of NEC Electronics products is "Standard" unless otherwise expressly specified in NEC Electronics data sheets or data books, etc. If customers wish to use NEC Electronics products in applications not intended by NEC Electronics, they must contact an NEC Electronics sales representative in advance to determine NEC Electronics' willingness to support a given application.

(Note)

- (1) "NEC Electronics" as used in this statement means NEC Electronics Corporation and also includes its majority-owned subsidiaries.
- (2) "NEC Electronics products" means any product developed or manufactured by or for NEC Electronics (as defined above).